

Smart Power High-Side-Switch for Industrial Applications



Features

- Overload protection
- Current limitation
- Short circuit protection
- Thermal shutdown with restart
- ESD Protection

Product Summary

Overvoltage protection	$V_{\rm bb(AZ)}$	62	V
Operating voltage	V _{bb(on)}	6 52	V
On-state resistance	R _{ON}	200	$m\Omega$
Nominal load current	I _{L(nom)}	1.3	Α
Operating temperature	T_{a}	-30+85	°C

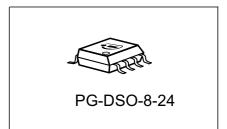
- Overvoltage protection (including load dump)
- Fast demagnetization of inductive loads
- Reverse battery protection with external resistor
- Open drain diagnostic output for overtemperature and short circuit
- Open load detection in OFF State with external resistor
- CMOS compatible input
- Loss of GND and loss of V_{bb} protection
- Very low standby current
- Green Product (RoHS Compliant)

Application

- All types of resistive, inductive and capacitive loads
- μC compatible power switch for 12 V, 24 V and 42 V DC industrial applications
- Replaces electromechanical relays and discrete circuits

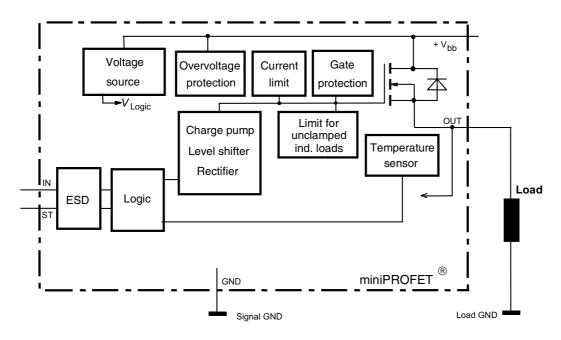


N channel vertical power FET with charge pump, ground referenced CMOS compatible input and diagnostic feedback, monolithically integrated in Smart SIPMOS® technology. Providing embedded protective functions.



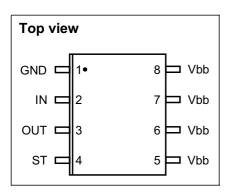


Block Diagram



Pin	Symbol	Function
1	GND	Logic ground
2	ZI	Input, activates the power switch in case of logic high signal
3	OUT	Output to the load
4	ST	Diagnostic feedback
5	Vbb	Positive power supply voltage
6	Vbb	Positive power supply voltage
7	Vbb	Positive power supply voltage
8	Vbb	Positive power supply voltage

Pin configuration





Maximum Ratings at T_i = 25 °C, unless otherwise specified

Parameter	Symbol	Value	Unit
Supply voltage	V _{bb}	52	V
Supply voltage for full short circuit protection	V _{bb(SC)}	50	
Continuous input voltage	V_{IN}	-10 +16	
Load current (Short - circuit current, see page 5)	IL	self limited	Α
Current through input pin (DC)	I _{IN}	± 5	mA
Junction temperature	T_{j}	150	°C
Operating temperature	T_{a}	-30+85	
Storage temperature	T _{stg}	-40 +105	
Power dissipation ¹⁾	P _{tot}	1.5	W
Inductive load switch-off energy dissipation 1)2)	E _{AS}	125	mJ
single pulse, (see page 9)			
Tj =150 °C, <i>I</i> _L = 1 A			
Load dump protection ²⁾ $V_{\text{LoadDump}}^{3)} = V_{\text{A}} + V_{\text{S}}$	V _{Loaddump}		V
$R_{\rm I}$ =2 Ω , $t_{\rm d}$ =400ms, $V_{\rm IN}$ = low or high, $V_{\rm A}$ =13,5V			
R_{L} = 13.5 Ω		73.5	
$R_{L} = 27 \Omega$		83.5	
Electrostatic discharge voltage (Human Body Model)	V _{ESD}		kV
according to ANSI EOS/ESD - S5.1 - 1993			
ESD STM5.1 - 1998			
Input pin		± 1	
all other pins		± 5	

Thermal Characteristics

Thermal resistance @ min. footprint	$R_{th(JA)}$	-	95	-	K/W
Thermal resistance @ 6 cm ² cooling area ¹⁾	$R_{th(JA)}$	-	70	83	

Data Sheet 3 Rev.1.1, 2008-09-26

¹Device on 50mm*50mm*1.5mm epoxy PCB FR4 with 6 cm2 (one layer, 70µm thick) copper area for drain connection. PCB is vertical without blown air. (see page 17)

²not subject to production test, specified by design

 $^{^{3}}V_{\text{Loaddump}}$ is setup without the DUT connected to the generator per ISO 7637-1 and DIN 40839 .

Supply voltages higher than $V_{bb(AZ)}$ require an external current limit for the GND pin, e.g. with a

 $^{150\}Omega$ resistor in GND connection. A resistor for the protection of the input is integrated.



Electrical Characteristics

Parameter and Conditions Symbol Values		Values		Unit			
at $T_{\rm j}$ = -40+150°C, $V_{\rm bb}$ = 1242V, unless otherwise specified		min.	typ.	max.			
Load Switching Capabilities and Characteristi	Load Switching Capabilities and Characteristics						
On-state resistance	R _{ON}				mΩ		
$T_{\rm j}$ = 25 °C, $I_{\rm L}$ = 1 A, $V_{\rm bb}$ = 952 V		_	150	200			
<i>T</i> _j = 150 °C		-	270	380			
Nominal load current; Device on PCB 1)	I _{L(nom)}	1.3	1.7	-	А		
$T_{\rm C}$ = 85 °C, $T_{\rm j}$ ≤ 150 °C							
Turn-on time to 90% V _{OUT}	t_{on}	-	80	180	μs		
R_{L} = 47 Ω							
Turn-off time to 10% V _{OUT}	$t_{\rm off}$	-	80	200			
R_{L} = 47 Ω							
Slew rate on 10 to 30% V _{OUT} ,	dV/dt _{on}	-	0.7	2	V/µs		
$R_{L} = 47 \ \Omega, \ V_{bb} = 13.5 \ V$							
Slew rate off 70 to 40% V _{OUT} ,	-dV/dt _{off}	-	0.9	2			
$R_{\rm L}$ = 47 Ω , $V_{\rm bb}$ = 13.5 V							

Operating Parameters

Operating voltage	V _{bb(on)}	6	-	52	V
Undervoltage shutdown of charge pump	V _{bb(under)}				
T _j = -40+85 °C		-	_	4	
$T_{j} = 150 ^{\circ}\text{C}$		-	-	5.5	
Undervoltage restart of charge pump	V _{bb(u cp)}	-	4	5.5	
Standby current	I _{bb(off)}				μΑ
$T_{\rm j}$ = -40+85 °C, $V_{\rm IN}$ = low		-	-	15	
$T_{\rm j}$ = +150 °C ²), $V_{\rm IN}$ = low		-	-	18	
Leakage output current (included in Ibb(off))	I _{L(off)}	-	-	5	
$V_{\text{IN}} = \text{low}$, ,				
Operating current	I _{GND}	-	0.8	2	mA
V_{IN} = high					

 $^{^1}Device$ on $50mm^*50mm^*1.5mm$ epoxy PCB FR4 with 6 cm2 (one layer, $70\mu m$ thick) copper area for drain connection. PCB is vertical without blown air. (see page 17)

²higher current due temperature sensor



Electrical Characteristics

Parameter and Conditions	Symbol		Values		Unit
at T_i = -40+150°C, V_{bb} = 1242V, unless otherwise specified		min.	typ.	max.	
Protection Functions ¹⁾	•				
Initial peak short circuit current limit (pin 5 to 3)	I _{L(SCp)}				Α
$T_{\rm j}$ = -40 °C, $V_{\rm bb}$ = 20 V, $t_{\rm m}$ = 150 $\mu {\rm s}$		-	-	9	
$T_{\rm j}$ = 25 °C		-	6.5	-	
<i>T</i> _j = 150 °C		4	-	-	
$T_{\rm j}$ = -40+150 °C, $V_{\rm bb}$ > 40 V , (see page 12)		-	52)	-	
Repetitive short circuit current limit	I _{L(SCr)}				
$T_j = T_{jt}$ (see timing diagrams)					
$V_{\rm bb}$ < 40 V		_	6	-	
$V_{\rm bb}$ > 40 V		-	4.5	-	
Output clamp (inductive load switch off)	V _{ON(CL)}	59	63	-	V
at $V_{\text{OUT}} = V_{\text{bb}} - V_{\text{ON(CL)}}$,					
$I_{\rm bb} = 4 \text{ mA}$					
Overvoltage protection ³⁾	V _{bb(AZ)}	62	-	-	
$I_{\rm bb} = 4 \text{ mA}$					
Thermal overload trip temperature	T _{it}	150	-	-	°C
Thermal hysteresis	$\Delta T_{\rm it}$	-	10	-	K
Reverse Battery					
Reverse battery ⁴⁾	-V _{bb}	-	-	52	V
Drain-source diode voltage ($V_{OUT} > V_{bb}$) $T_i = 150 ^{\circ}\text{C}$	-V _{ON}	-	600	-	mV

Data Sheet 5 Rev.1.1, 2008-09-26

¹Integrated protection functions are designed to prevent IC destruction under fault conditions described in the data sheet. Fault conditions are considered as "outside" normal operating range. Protection functions are not designed for continuous repetitive operation.

²not subject to production test, specified by design

 $^{^{3}}$ see also $V_{\mbox{ON(CL)}}$ in circuit diagram on page 8

 $^{^4}$ Requires a 150 Ω resistor in GND connection. The reverse load current through the intrinsic drain-source diode has to be limited by the connected load. Power dissipation is higher compared to normal operating conditions due to the voltage drop across the drain-source diode. The temperature protection is not active during reverse current operation! Input current has to be limited (see max. ratings page 3).



Electrical Characteristics

Parameter	Symbol		Values		Unit
at T_i = -40+150°C, V_{bb} = 1242V, unless otherwise specified		min.	typ.	max.	
Input and Status feedback	•	•	•		•
Input turn-on threshold voltage	$V_{\rm IN(T+)}$	-	-	2.2	V
Input turn-off threshold voltage	$V_{\rm IN(T-)}$	0.8	-	-	
Input threshold hysteresis	$\Delta V_{\rm IN(T)}$	-	0.4	-	
Off state input current	I _{IN(off)}	1	-	25	μA
V _{IN} = 0.7 V					
On state input current	I _{IN(on)}	3	-	25	
V _{IN} = 5 V					
Status output (open drain), Zener limit voltage	V _{ST(high)}	5.4	6.1	-	V
<i>I</i> _{ST} = 1.6 mA					
Status output (open drain), ST low voltage	V _{ST(low)}				
$T_{\rm j}$ = -40+25 °C, $I_{\rm ST}$ = 1.6 mA		-	-	0.4	
$T_{\rm j}$ = 150 °C, $I_{\rm ST}$ = 1.6 mA		-	-	0.6	
Status invalid after positive input slope 1)	$t_{d(ST+)}$	-	120	160	μs
$V_{\rm bb}$ = 20 V					
Status invalid after negative input slope 1)	t _{d(ST-)}	_	250	400	
Input resistance (see page 8)	R_{I}	2	3.5	5	kΩ

Diagnostic Characteristics

Short circuit detection voltage	V _{OUT(SC)}	-	2.8	-	V
Open load detection voltage ²⁾	V _{OUT(OL)}	-	3	4	
Internal output pull down ³⁾	RO				kΩ
(see page 9 and 14)					
$V_{\text{OUT(OL)}} = 4 \text{ V}$		-	200	-	

¹no delay time after overtemperature switch off and short circuit in on-state

²External pull up resistor required for open load detection in off state.

³not subject to production test, specified by design



	Input	Output	Status
	level	level	
Normal	L	L	Н
operation	Н	Н	Н
Short circuit	L	L	Н
to GND	Н	L *	L
Short circuit to	L	Н	L
V _{bb} (in off-state)	Н	Н	Н
Overload	L	L	Н
	Н	H **	Н
Overtemperature	L	L	н
	Н	L	L
Open Load in	L	Z	H (L ¹⁾)
off-state	Н	Н	Н

^{*)} Out ="L": V_{OUT} < 2.8V typ.

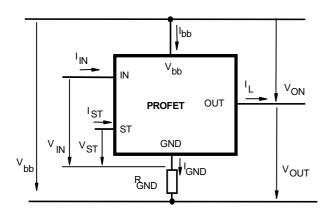
^{**)} Out ="H": $V_{OUT} > 2.8V$ typ.

Z = high impedance, potential depends on external circuit

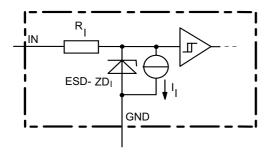
 $^{^{1}\}mbox{with external resistor between V_{bb} and OUT}$



Terms

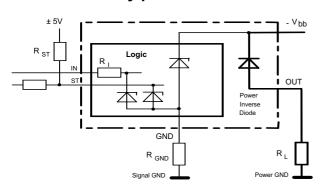


Input circuit (ESD protection)



The use of ESD zener diodes as voltage clamp at DC conditions is not recommended

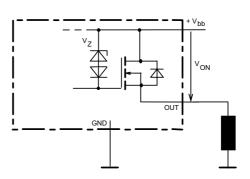
Reverse battery protection



 R_{GND} =150 Ω , R_{I} =3.5 $k\Omega$ typ.,

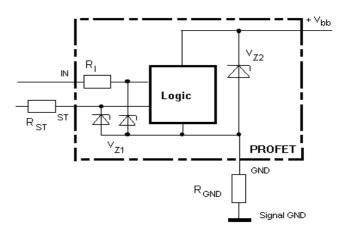
Temperature protection is not active during inverse current

Inductive and overvoltage output clamp



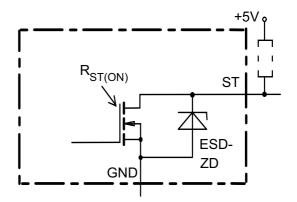
V_{ON} clamped to 59V min.

Overvoltage protection of logic part



 $\begin{aligned} &\text{V}_{Z1}\text{=}6.1\text{V typ., V}_{Z2}\text{=}\text{V}_{bb(AZ)}\text{=}62\text{V min.,} \\ &\text{R}_{I}\text{=}3.5 \text{ k}\Omega \text{ typ., R}_{GND}\text{=}150\Omega \end{aligned}$

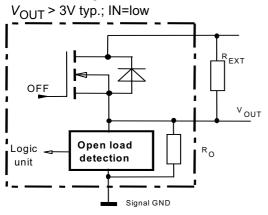
Status output



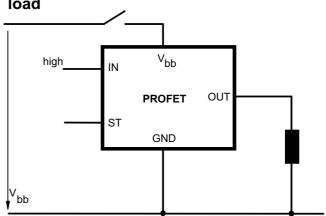


Open-load detection

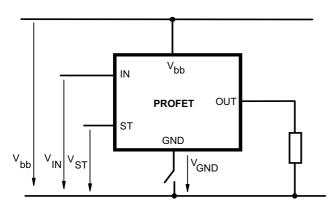
OFF-state diagnostic condition:



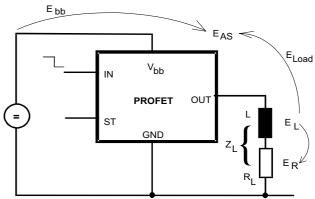
V_{bb} disconnect with charged inductive load



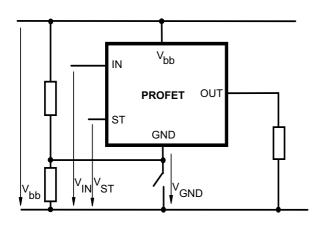
GND disconnect



Inductive Load switch-off energy dissipation



GND disconnect with GND pull up



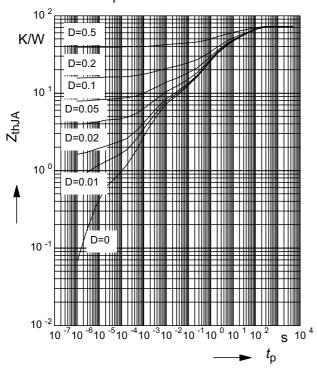
Energy stored in load inductance: $E_L = \frac{1}{2} * L * I_L^2$ While demagnetizing load inductance, the energy dissipated in PROFET is $E_{AS} = E_{bb} + E_L - E_R = V_{ON(CL)} * i_L(t) dt$, with an approximate solution for $R_L > 0\Omega$:

$$E_{AS} = \frac{I_L * L}{2 * R_L} * (V_{bb} + |V_{OUT(CL)|}) * \ln(1 + \frac{I_L * R_L}{|V_{OUT(CL)|}})$$



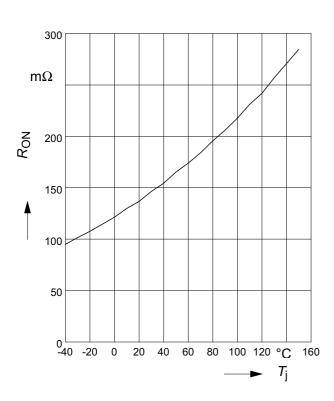
Typ. transient thermal impedance Z_{thJA} =f(t_{p}) @ 6cm² heatsink area

Parameter: $D=t_{D}/T$



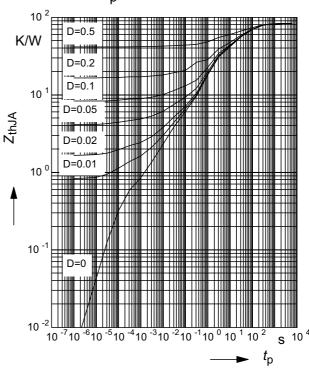
Typ. on-state resistance

$$R_{ON} = f(T_i)$$
; $V_{bb} = 13,5V$; $V_{in} = high$



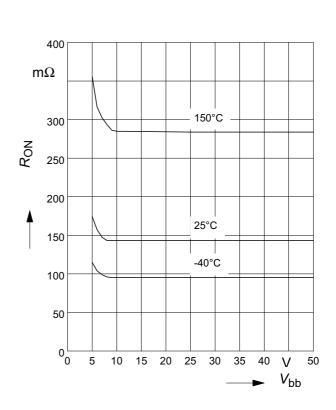
Typ. transient thermal impedance Z_{thJA} =f(t_{p}) @ min. footprint

Parameter: $D=t_D/T$



Typ. on-state resistance

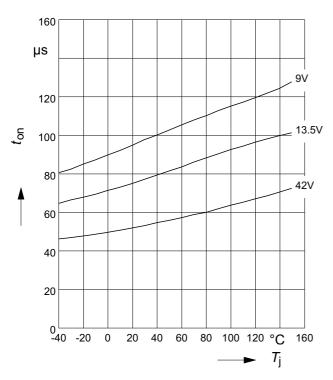
$$R_{ON} = f(V_{bb}); I_L = 1 \text{ A}; V_{in} = \text{high}$$



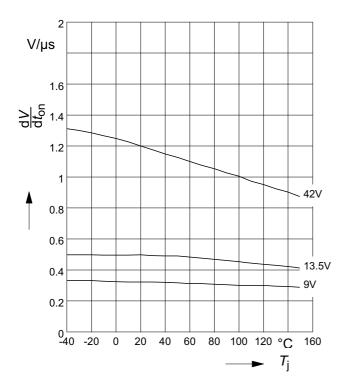


Typ. turn on time

$$t_{on} = f(T_j); R_L = 47\Omega$$

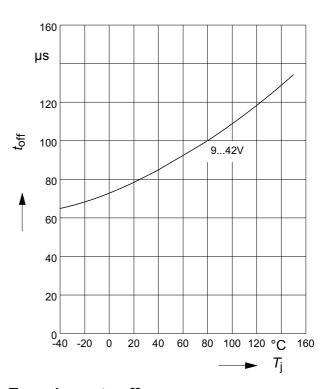


Typ. slew rate on $dV/dt_{on} = f(T_j)$; $R_L = 47 \Omega$



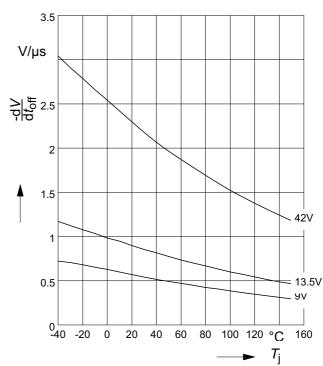
Typ. turn off time

$$t_{\text{off}} = f(T_j); R_L = 47\Omega$$



Typ. slew rate off

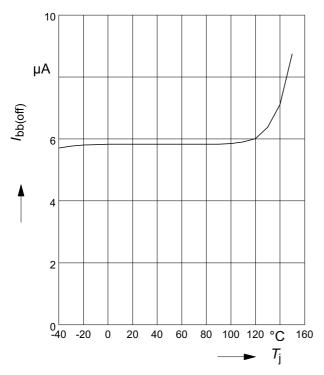
$$dV/dt_{off} = f(T_j); R_L = 47 \Omega$$



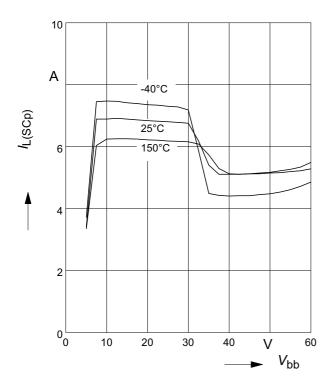


Typ. standby current

$$I_{bb(off)} = f(T_j)$$
; $V_{bb} = 42V$; $V_{IN} = low$

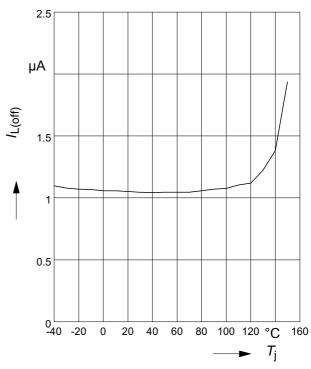


Typ. initial peak short circuit current limit $I_{L(SCp)} = f(V_{bb})$

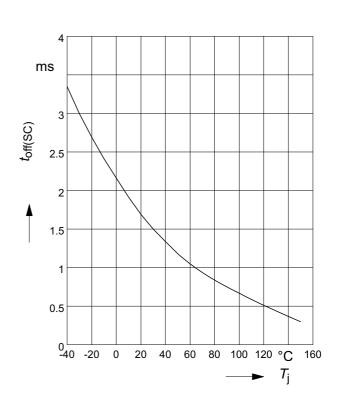


Typ. leakage current

$$I_{L(off)} = f(T_j)$$
; $V_{bb} = 42V$; $V_{IN} = low$



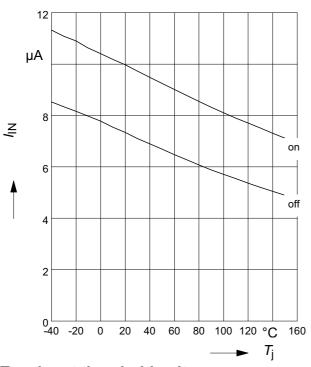
Typ. initial short circuit shutdown time $t_{off(SC)} = f(T_{j,start})$; $V_{bb} = 20V$





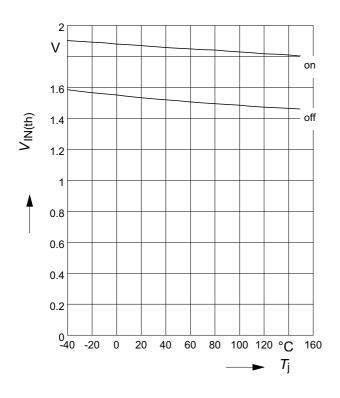
Typ. input current

 $I_{\text{IN(on/off)}} = f(T_j); V_{\text{bb}} = 13,5V; V_{\text{IN}} = \text{low/high}$ $V_{\text{INlow}} \le 0,7V; V_{\text{INhigh}} = 5V$



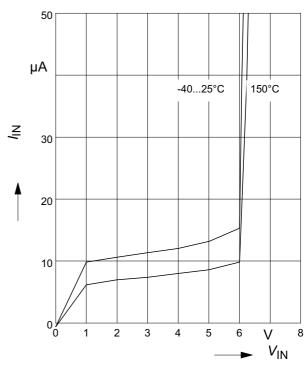
Typ. input threshold voltage

 $V_{\text{IN(th)}} = f(T_{\text{j}}) ; V_{\text{bb}} = 13,5 \text{V}$



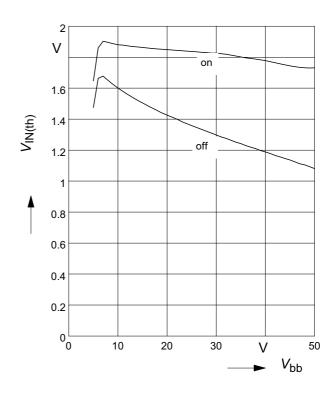
Typ. input current

 $I_{IN} = f(V_{IN}); V_{bb} = 13.5V$



Typ. input threshold voltage

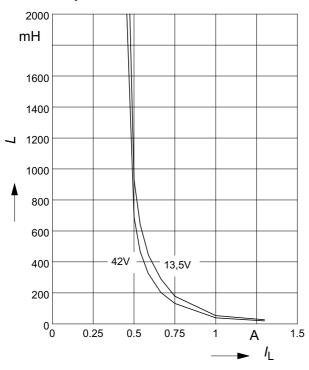
 $V_{IN(th)} = f(V_{bb})$; $T_j = 25$ °C





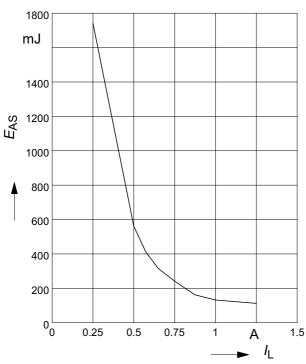
Maximum allowable load inductance for a single switch off

$$\boldsymbol{L} = \mathbf{f}(\boldsymbol{I_L}); \ T_{\text{jstart}} = 150^{\circ}\text{C}, \ R_{\text{L}} = 0\Omega$$



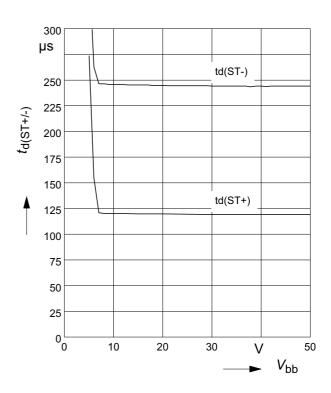
Maximum allowable inductive switch-off energy, single pulse

$$E_{AS} = f(I_L); T_{jstart} = 150$$
°C, $V_{bb} = 13,5$ V



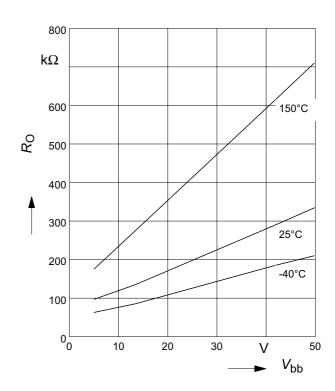
Typ. status delay time

$$t_{d(ST)} = f(V_{bb}); T_j = 25^{\circ}C$$



Typ. internal output pull down

$$R_{\rm O} = f(V_{\rm bb})$$





Timing diagrams

Figure 1a: Vbb turn on:

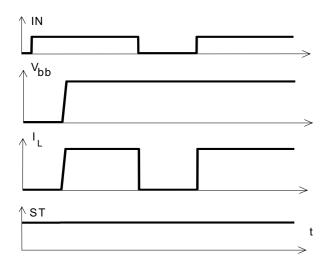


Figure 2b: Switching a lamp,

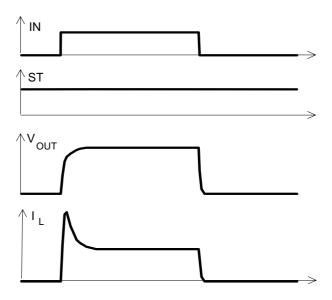


Figure 2a: Switching a resistive load, turn-on/off time and slew rate definition

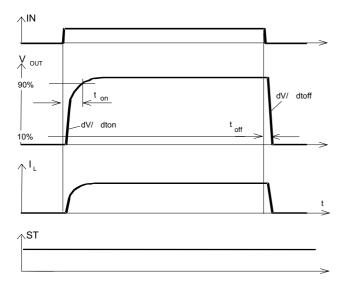


Figure 2c: Switching an inductive load

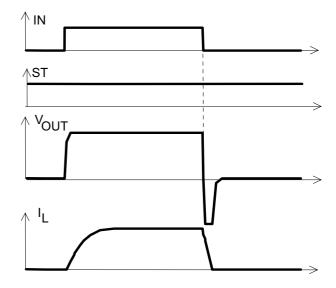
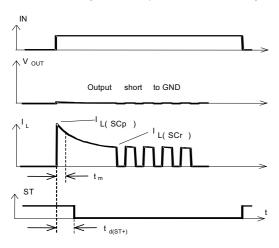




Figure 3a: Turn on into short circuit, shut down by overtemperature, restart by cooling



Heating up of the chip may require several milliseconds, depending on external conditions.

Figure 4: Overtemperature: Reset if $T_i < T_{it}$

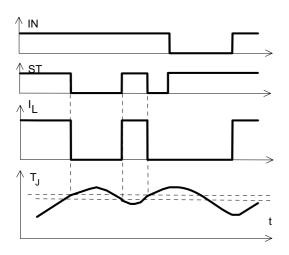


Figure 3b: Short circuit in on-state shut down by overtemperature, restart by cooling

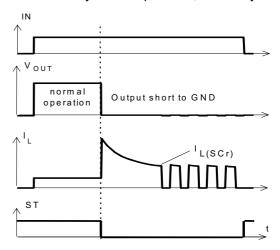
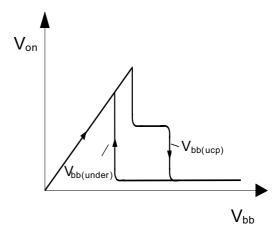


Figure 5: Undervoltage restart of charge pump





Package Outlines

1 Package Outlines

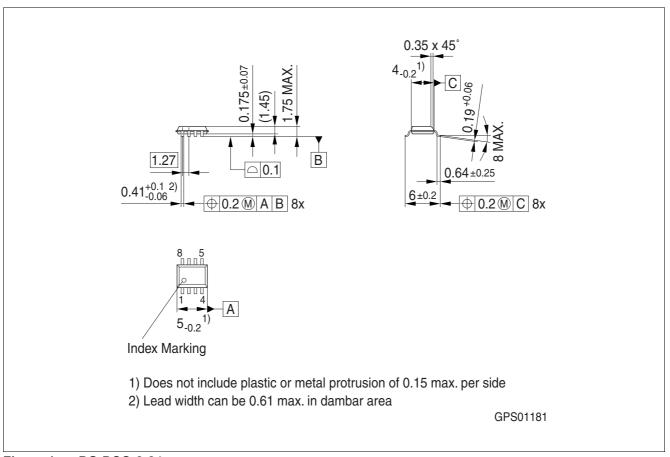


Figure 1 PG-DSO-8-24

Green Product (RoHS compliant)

To meet the world-wide customer requirements for environmentally friendly products and to be compliant with government regulations the device is available as a green product. Green products are RoHS-Compliant (i.e Pb-free finish on leads and suitable for Pb-free soldering according to IPC/JEDEC J-STD-020).



Revision History

2 Revision History

Revision	Date	Changes
1.1	2008-09-26	all pages: added new Infineon logo Initial version of RoHS-compliant derivate of the ISP752R Page 1 and 17: added RoHS compliance statement and Green Product feature Page 1, 17: Package changed to RoHS compliant version
		Page 18: added Revision history
		Page 19: update of disclaimer

Edition 2008-09-26

Published by Infineon Technologies AG 81726 Munich, Germany © 2008 Infineon Technologies AG All Rights Reserved.

Legal Disclaimer

The information given in this document shall in no event be regarded as a guarantee of conditions or characteristics. With respect to any examples or hints given herein, any typical values stated herein and/or any information regarding the application of the device, Infineon Technologies hereby disclaims any and all warranties and liabilities of any kind, including without limitation, warranties of non-infringement of intellectual property rights of any third party.

Information

For further information on technology, delivery terms and conditions and prices, please contact the nearest Infineon Technologies Office (www.infineon.com).

Warnings

Due to technical requirements, components may contain dangerous substances. For information on the types in question, please contact the nearest Infineon Technologies Office.

Infineon Technologies components may be used in life-support devices or systems only with the express written approval of Infineon Technologies, if a failure of such components can reasonably be expected to cause the failure of that life-support device or system or to affect the safety or effectiveness of that device or system. Life support devices or systems are intended to be implanted in the human body or to support and/or maintain and sustain and/or protect human life. If they fail, it is reasonable to assume that the health of the user or other persons may be endangered.

Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

Infineon:

ISP752R ISP752RFUMA1



Компания «Океан Электроники» предлагает заключение долгосрочных отношений при поставках импортных электронных компонентов на взаимовыгодных условиях!

Наши преимущества:

- Поставка оригинальных импортных электронных компонентов напрямую с производств Америки, Европы и Азии, а так же с крупнейших складов мира;
- Широкая линейка поставок активных и пассивных импортных электронных компонентов (более 30 млн. наименований);
- Поставка сложных, дефицитных, либо снятых с производства позиций;
- Оперативные сроки поставки под заказ (от 5 рабочих дней);
- Экспресс доставка в любую точку России;
- Помощь Конструкторского Отдела и консультации квалифицированных инженеров;
- Техническая поддержка проекта, помощь в подборе аналогов, поставка прототипов;
- Поставка электронных компонентов под контролем ВП;
- Система менеджмента качества сертифицирована по Международному стандарту ISO 9001;
- При необходимости вся продукция военного и аэрокосмического назначения проходит испытания и сертификацию в лаборатории (по согласованию с заказчиком);
- Поставка специализированных компонентов военного и аэрокосмического уровня качества (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Actel, Aeroflex, Peregrine, VPT, Syfer, Eurofarad, Texas Instruments, MS Kennedy, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits, General Dynamics и др.);

Компания «Океан Электроники» является официальным дистрибьютором и эксклюзивным представителем в России одного из крупнейших производителей разъемов военного и аэрокосмического назначения «JONHON», а так же официальным дистрибьютором и эксклюзивным представителем в России производителя высокотехнологичных и надежных решений для передачи СВЧ сигналов «FORSTAR».



«JONHON» (основан в 1970 г.)

Разъемы специального, военного и аэрокосмического назначения:

(Применяются в военной, авиационной, аэрокосмической, морской, железнодорожной, горно- и нефтедобывающей отраслях промышленности)

«**FORSTAR**» (основан в 1998 г.)

ВЧ соединители, коаксиальные кабели, кабельные сборки и микроволновые компоненты:

(Применяются в телекоммуникациях гражданского и специального назначения, в средствах связи, РЛС, а так же военной, авиационной и аэрокосмической отраслях промышленности).



Телефон: 8 (812) 309-75-97 (многоканальный)

Факс: 8 (812) 320-03-32

Электронная почта: ocean@oceanchips.ru

Web: http://oceanchips.ru/

Адрес: 198099, г. Санкт-Петербург, ул. Калинина, д. 2, корп. 4, лит. А